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MM74HC4316 **Quad Analog Switch with Level Translator**

General Description

The MM74HC4316 devices are digitally controlled analog switches implemented in advanced silicon-gate CMOS technology. These switches have low "ON" resistance and low "OFF" leakages. They are bidirectional switches, thus any analog input may be used as an output and vice-versa. Three supply pins are provided on the MM74HC4316 to implement a level translator which enables this circuit to operate with 0–6V logic levels and up to \pm 6V analog switch levels. The MM74HC4316 also has a common enable input in addition to each switch's control which when LOW will disable all switches to their OFF state. All analog inputs and outputs and digital inputs are protected from electrostatic damage by diodes to V_{CC} and ground.

February 1984

Revised February 1999

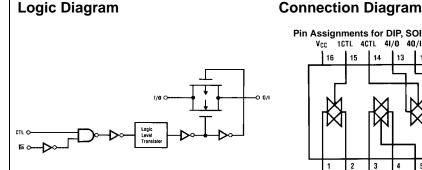
Features

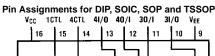
- Typical switch enable time: 20 ns
- Wide analog input voltage range: ±6V
- Low "ON" resistance:
- 50 typ. (V_{CC}–V_{EE} = 4.5V) 30 typ. (V_{CC}–V_{EE} = 9V)
- Low quiescent current: 80 μA maximum (74HC)
- Matched switch characteristics
- Individual switch controls plus a common enable

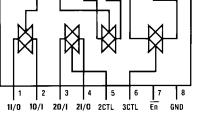
Ordering Code:

Order Number	Package Number	Package Description
MM74HC4316M	M16A	16-Lead Small Outline Integrated Package (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC4316SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC4316MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-1536, 4.4mm Wide
MM74HC4316N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.







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Top View

Truth Table

Inp	Inputs		
En	CTL	I/O–O/I	
н	Х	"OFF"	
L	L	"OFF"	
L	Н	"ON"	

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(Note 2)

Absolute Maximum Ratings(Note 1)

Recommended Operating Conditions

Supply Voltage (V _{CC})	-0.5 to +7.5V
Supply Voltage (V _{EE})	+0.5 to -7.5V
DC Control Input Voltage (VIN)	-1.5 to V _{CC} $+1.5$ V
DC Switch I/O Voltage (VIO)	$V_{\text{EE}}0.5$ to V_{CC} +0.5V
Clamp Diode Current (I _{IK} , I _{OK})	±20 mA
DC Output Current, per pin (I _{OUT})	±25 mA
DC V_{CC} or GND Current, per pin (I _{CC})	±50 mA
Storage Temperature Range (T _{STG})	-65°C to +150°C
Power Dissipation (P _D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature (T _L)	
(Soldering 10 seconds)	260°C

	Min	Max	Units
Supply Voltage (V _{CC})	2	6	V
Supply Voltage (V _{EE})	0	-6	V
DC Input or Output Voltage			
(V _{IN} , V _{OUT})	0	V _{CC}	V
Operating Temperature Range (T _A)	-40	+85	°C
Input Rise or Fall Times			
$(t_r,t_f)\ V_{CC}=2.0V$		1000	ns
$V_{CC} = 4.5V$		500	ns
$V_{CC} = 6.0V$		400	ns
$V_{CC} = 12.0V$		250	ns

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground. Note 3: Power Dissipation temperature derating — plastic "N" package: – 12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	V_{EE}	v _{cc}	$T_A = 25^{\circ}C$		$T_A = -40$ to $85^{\circ}C$	$T_A = -55$ to $125^{\circ}C$	Units
	Faiametei				Тур		Guaranteed I	imits	Units
VIH	Minimum HIGH Level			2.0V		1.5	1.5	1.5	V
	Input Voltage			4.5V		3.15	3.15	3.15	V
				6.0V		4.2	4.2	4.2	V
V _{IL}	Maximum LOW Level			2.0V		0.5	0.5	0.5	V
	Input Voltage			4.5V		1.35	1.35	1.35	V
				6.0V		1.8	1.8	1.8	V
R _{ON}	Minimum "ON" Resistance	$V_{CTL} = V_{IH}, I_S = 2.0 \text{ mA}$	GND	4.5V	100	170	200	220	Ω
	(Note 5)	$V_{IS} = V_{CC}$ to V_{EE}	-4.5V	4.5V	40	85	105	110	Ω
		(Figure 1)	-6.0V	6.0V	30	70	85	90	Ω
			GND	2.0V	100	180	215	240	Ω
		$V_{CTL} = V_{IH}, I_S = 2.0 \text{ mA}$	GND	4.5V	40	80	100	120	Ω
		$V_{IS} = V_{CC} \text{ or } V_{EE}$	-4.5V	4.5V	50	60	75	80	Ω
		(Figure 1)	-6.0V	6.0V	20	40	60	70	Ω
R _{ON}	Maximum "ON" Resistance	V _{CTL} = V _{IH}	GND	4.5V	10	15	20	20	Ω
	Matching	$V_{IS} = V_{CC}$ to V_{EE}	-4.5V	4.5V	5	10	15	15	Ω
			-6.0V	6.0V	5	10	15	15	Ω
I _{IN}	Maximum Control Input Current	$V_{IN} = V_{CC}$ or GND	GND	6.0V		±0.1	±1.0	±1.0	μA
I _{IZ}	Maximum Switch "OFF"	$V_{OS} = V_{CC}$ or V_{EE}	GND	6.0V		±60	±600	±600	nA
	Leakage Current	$V_{IS} = V_{EE}$ or V_{CC}	-6.0V	6.0V		±100	±1000	±1000	nA
		V _{CTL} = V _{IL} (Figure 2)							
I _{IZ}	Maximum Switch "ON"	V _{IS} = V _{CC} to V _{EE}	GND	6.0V		±40	±150	±150	nA
	Leakage Current	$V_{CTL} = V_{IH}, V_{OS} = OPEN$ (Figure 3)	-6.0V	6.0V		±60	±300	±300	nA
I _{CC}	Maximum Quiescent	$V_{IN} = V_{CC}$ or GND	GND	6.0V		2.0	20	40	μA
	Supply Current	$I_{OUT} = 0 \mu A$	-6.0V	6.0V		8.0	80	160	μA

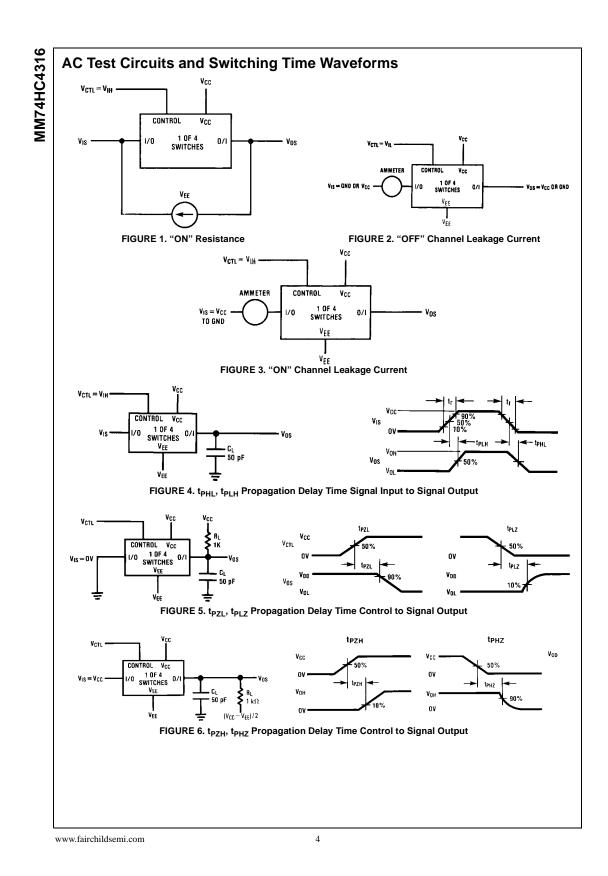
Note 4: For a power supply of 5V \pm 10% the worst case on resistances (R_{ON}) occurs for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC}=5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current occurs for CMOS at the higher voltage and so the 5.5V values should be used.

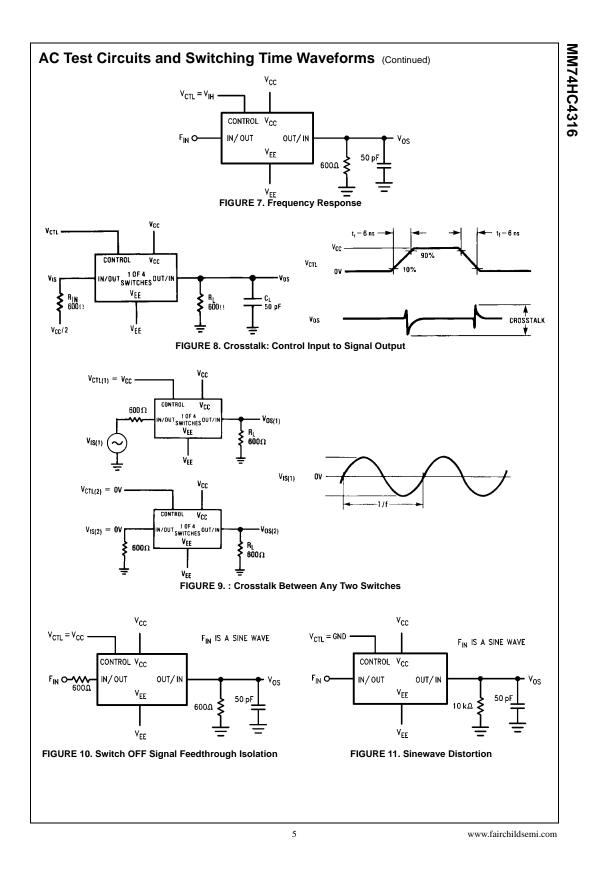
Note 5: At supply voltages (V_{CC}-V_{EE}) approaching 2V the analog switch on resistance becomes extremely non-linear. Therefore it is recommended that these devices be used to transmit digital only when using these supply voltages.

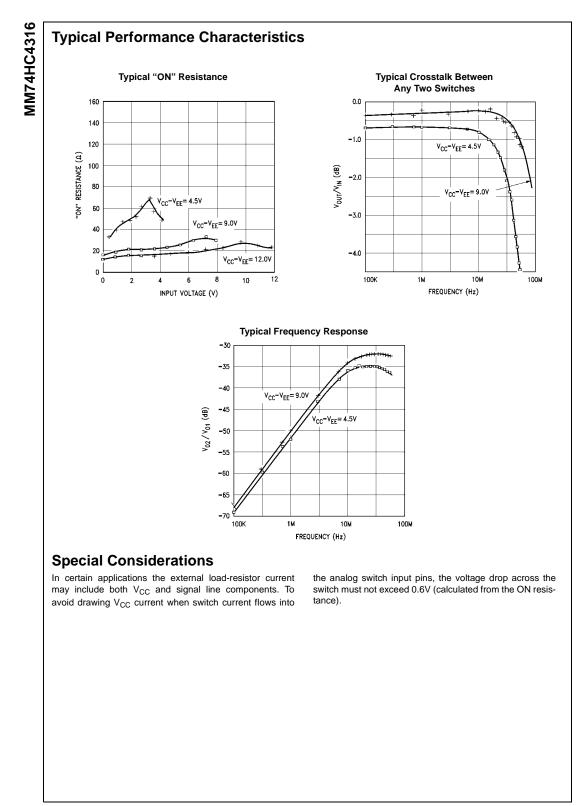
C. make al	Desembles	Conditions	v	v	T _A = -	+25°C	$T_A = -40^{\circ}C$ to $+85^{\circ}C$	$T_{A}=-55^{\circ}C$ to $+125^{\circ}C$	Unite
Symbol	Parameter	Conditions	VEE	Vcc	Тур		Guaranteed I	limits	Units
t _{PHL} ,	Maximum Propagation		GND	2.0V	25	50	63	75	ns
t _{PLH}	Delay Switch		GND	4.5V	5	10	13	15	ns
	In to Out		-4.5V	4.5V	4	8	12	14	ns
			-6.0V	6.0V	3	7	11	13	ns
t _{PZL} ,	Maximum Switch	$R_L = 1 k\Omega$	GND	2.0V	30	165	206	250	ns
t _{PZH}	Turn "ON" Delay		GND	4.5V	20	35	43	53	ns
	(Control)		-4.5V	4.5V	15	32	39	48	ns
			-6.0V	6.0V	14	30	37	45	ns
t _{PHZ} ,	Maximum Switch	$R_L = 1 k\Omega$	GND	2.0V	45	250	312	375	ns
t _{PLZ}	Turn "OFF" Delay		GND	4.5V	25	50	63	75	ns
	(Control)		-4.5V	4.5V	20	44	55	66	ns
			-6.0V	6.0V	20	44	55	66	
t _{PZL} ,	Maximum Switch		GND	2.0V	35	205	256	308	ns
t _{PZH}	Turn "ON" Delay		GND	4.5V	20	41	52	62	ns
	(Enable)		-4.5V	4.5V	19	38	48	57	ns
			-6.0V	6.0V	18	36	45	54	ns
t _{PLZ} ,	Maximum Switch		GND	2.0V	58	265	330	400	ns
t _{PHZ}	Turn "OFF" Delay		GND	4.5V	28	53	67	79	ns
	(Enable)		-4.5V	4.5V	23	47	59	70	ns
			-6.0V	6.0V	21	47	59	70	ns
f _{MAX}	Minimum Frequency	$R_L = 600\Omega$, $V_{IS} = 2V_{PP}$	0V	4.5	40				MHz
	Response (Figure 7)	at (V _{CC} -V _{EE} /2)	-4.5V	4.5V	100				MHz
	20 log (V _{OS} /V _{IS})=-3 dB	(Note 6) (Note 7)							
	Control to Switch	$R_L = 600\Omega$, $F = 1 MHz$	0V	4.5V	100				mV
	Feedthrough Noise	$C_L = 50 \text{ pF}$	-4.5V	4.5V	250				mV
	(Figure 8)	(Note 7) (Note 8)							
	Crosstalk Between	$R_L = 600\Omega$, $F = 1 MHz$							
	any Two Switches		0V	4.5V	-52				dB
	(Figure 9)		-4.5V	4.5V	-50				dB
	Switch OFF Signal	$R_L = 600\Omega$, $F = 1 MHz$							
	Feedthrough Isolation	$V_{CTL} = V_{IL}$,	0V	4.5V	-42				dB
	(Figure 10)	(Note 7) (Note 8)	-4.5V	4.5V	-44				dB
THD	Sinewave Harmonic	$R_L = 10 \text{ K}\Omega, C_L = 50 \text{ pF},$							
	Distortion	F = 1 KHz							
	(Figure 11)	$V_{IS} = 4V_{PP}$	0V	4.5V	0.013				%
		$V_{IS} = 8V_{PP}$	-4.5V	4.5V	0.008				%
C _{IN}	Maximum Control				5				pF
	Input Capacitance								
	Maximum Switch				35				pF
C _{IN}									
C _{IN}	Input Capacitance				0.5				pF
C _{IN} C _{IN}	Input Capacitance Maximum Feedthrough	V _{CTL} = GND			0.0				P
		V _{CTL} = GND			0.0				F.
	Maximum Feedthrough	V _{CTL} = GND			15				pF

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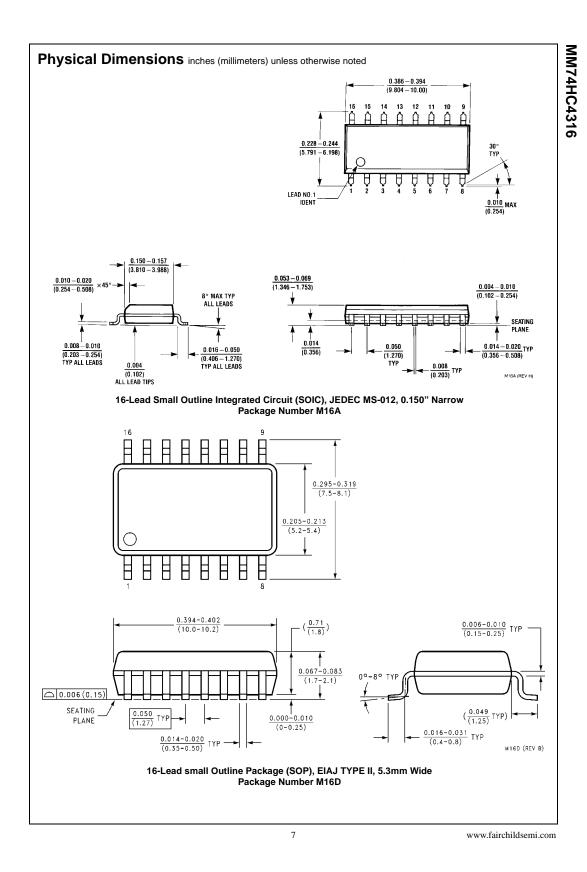


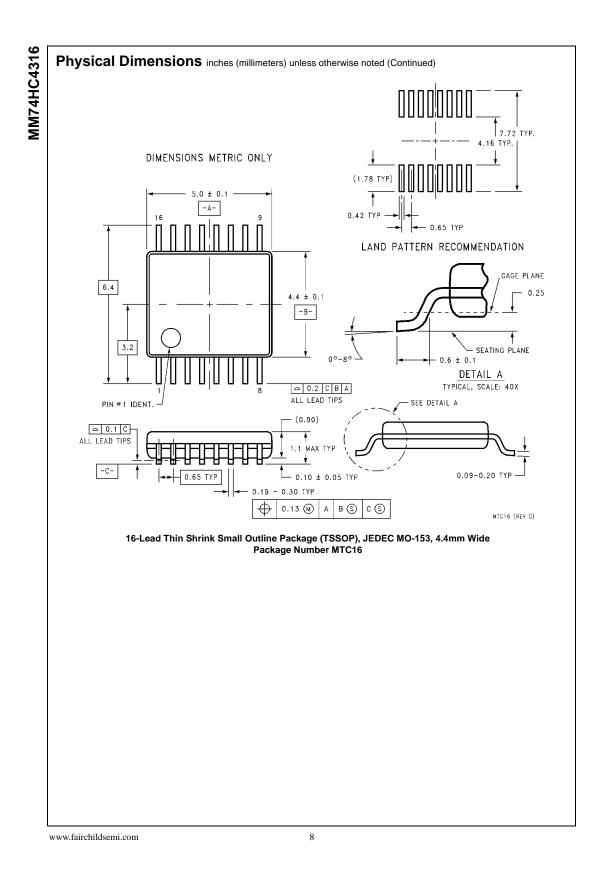


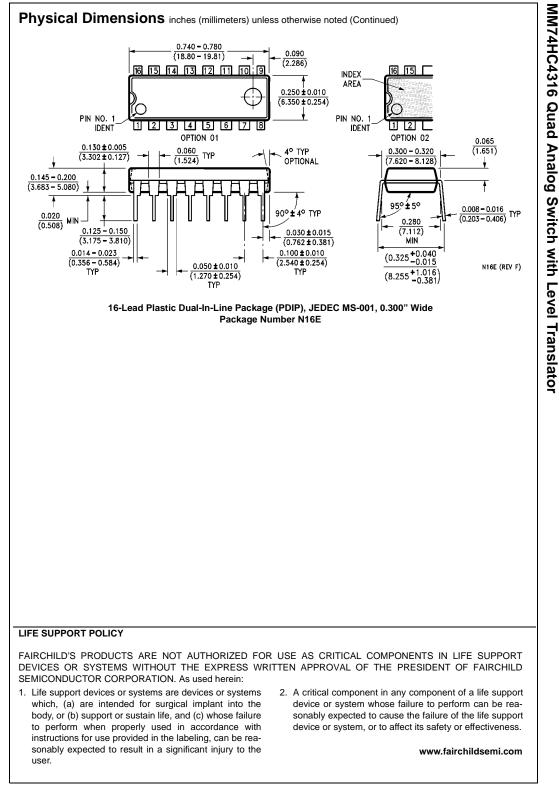


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